

To our customers,

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## Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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# MOS FIELD EFFECT TRANSISTOR

# NP110N055PUG

## SWITCHING

### N-CHANNEL POWER MOS FET

#### DESCRIPTION

The NP110N055PUG is N-channel MOS Field Effect Transistor designed for high current switching applications.

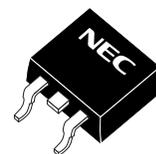
#### ORDERING INFORMATION

PART NUMBER	PACKAGE
NP110N055PUG	TO-263 (MP-25ZP)

#### FEATURES

- Channel temperature 175 degree rating
- Super low on-state resistance  
 $R_{DS(on)} = 2.4 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 55 \text{ A)}$
- Low  $C_{iss}$ :  $C_{iss} = 17100 \text{ pF TYP.}$

(TO-263)



#### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ )

Drain to Source Voltage ( $V_{GS} = 0 \text{ V}$ )	$V_{DSS}$	55	V
Gate to Source Voltage ( $V_{DS} = 0 \text{ V}$ )	$V_{GSS}$	$\pm 20$	V
Drain Current (DC) ( $T_C = 25^\circ\text{C}$ )	$I_{D(DC)}$	$\pm 110$	A
Drain Current (pulse) <sup>Note1</sup>	$I_{D(pulse)}$	$\pm 440$	A
Total Power Dissipation ( $T_A = 25^\circ\text{C}$ )	$P_{T1}$	1.8	W
Total Power Dissipation ( $T_C = 25^\circ\text{C}$ )	$P_{T2}$	288	W
Channel Temperature	$T_{ch}$	175	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-55 to +175	$^\circ\text{C}$
Repetitive Avalanche Current <sup>Note2</sup>	$I_{AR}$	66	A
Repetitive Avalanche Energy <sup>Note2</sup>	$E_{AR}$	435	mJ

**Notes 1.**  $PW \leq 10 \mu\text{s}$ , Duty Cycle  $\leq 1\%$

**2.**  $T_{ch} \leq 150^\circ\text{C}$ ,  $V_{DD} = 28 \text{ V}$ ,  $R_G = 25 \Omega$ ,  $V_{GS} = 20 \rightarrow 0 \text{ V}$

#### THERMAL RESISTANCE

Channel to Case Thermal Resistance	$R_{th(ch-C)}$	0.52	$^\circ\text{C/W}$
Channel to Ambient Thermal Resistance	$R_{th(ch-A)}$	83.3	$^\circ\text{C/W}$

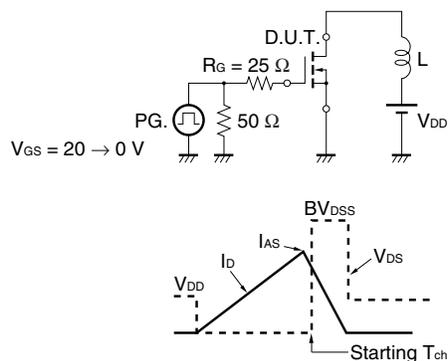
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**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)**

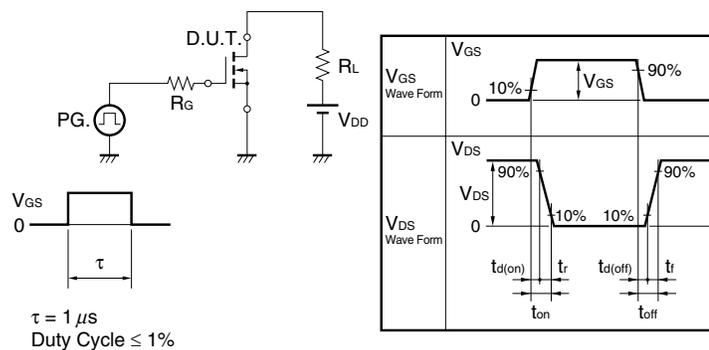
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 55 V, V <sub>GS</sub> = 0 V			1	μA
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V			±100	nA
Gate to Source Threshold Voltage <sup>Note</sup>	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA	2.0	3.0	4.0	V
Forward Transfer Admittance <sup>Note</sup>	y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 55 A	42	83		S
Drain to Source On-state Resistance <sup>Note</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 55 A		1.9	2.4	mΩ
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 25 V		17100	25700	pF
Output Capacitance	C <sub>oss</sub>	V <sub>GS</sub> = 0 V		1120	1680	pF
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1 MHz		725	1310	pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 28 V, I <sub>D</sub> = 55 A		63	140	ns
Rise Time	t <sub>r</sub>	V <sub>GS</sub> = 10 V		201	510	ns
Turn-off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> = 0 Ω		131	270	ns
Fall Time	t <sub>f</sub>			19	50	ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = 44 V		251	380	nC
Gate to Source Charge	Q <sub>GS</sub>	V <sub>GS</sub> = 10 V		63		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = 110 A		81		nC
Body Diode Forward Voltage <sup>Note</sup>	V <sub>F(S-D)</sub>	I <sub>F</sub> = 110 A, V <sub>GS</sub> = 0 V		0.9	1.5	V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 110 A, V <sub>GS</sub> = 0 V		58		ns
Reverse Recovery Charge	Q <sub>rr</sub>	di/dt = 100 A/μs		87		nC

**Note** Pulsed

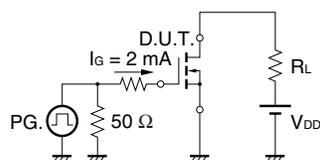
**TEST CIRCUIT 1 AVALANCHE CAPABILITY**



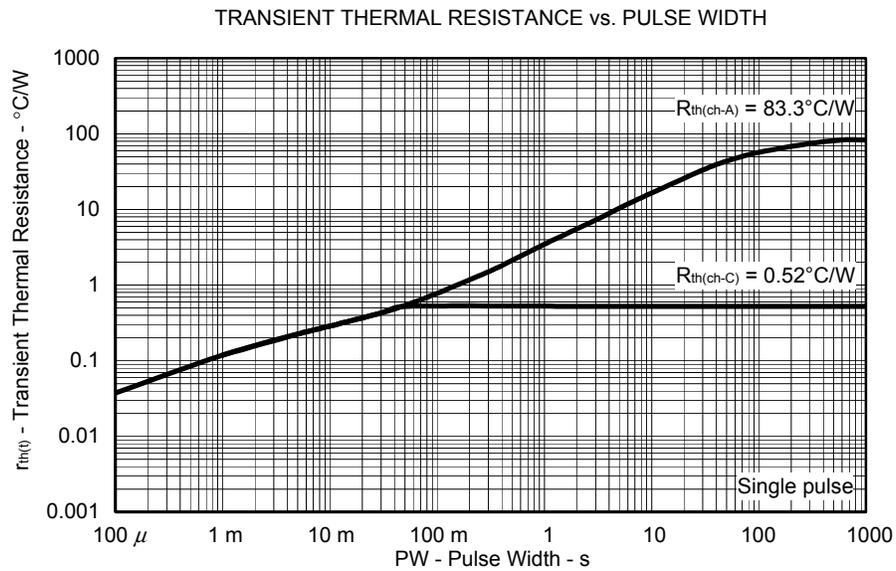
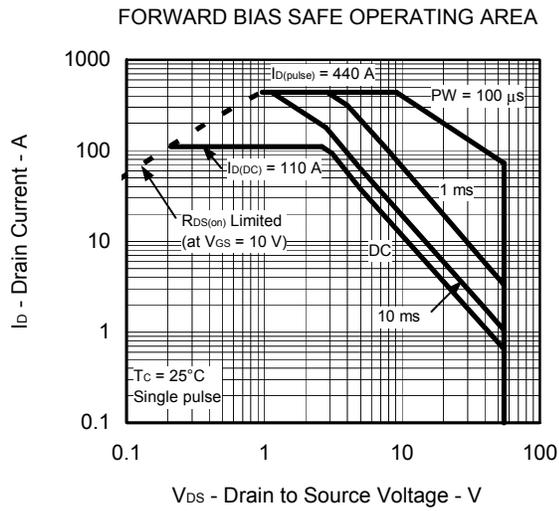
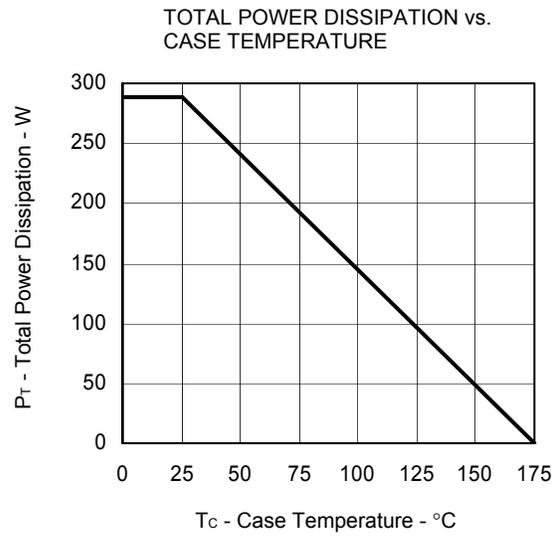
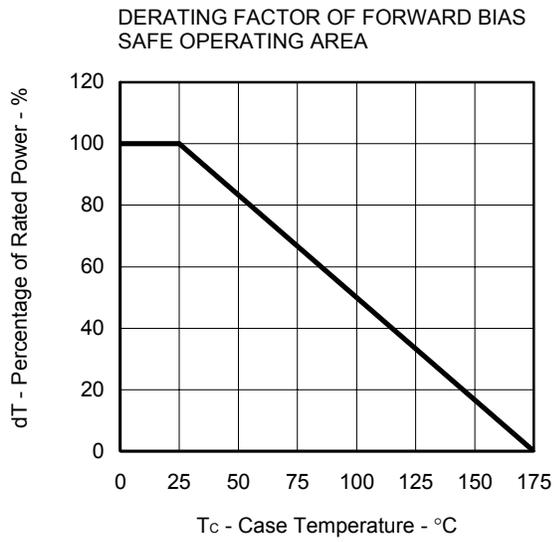
**TEST CIRCUIT 2 SWITCHING TIME**



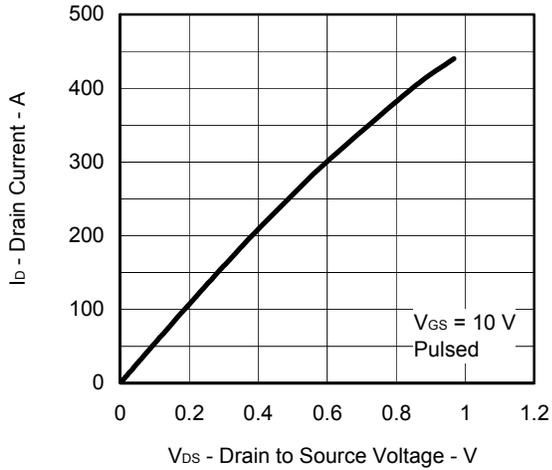
**TEST CIRCUIT 3 GATE CHARGE**



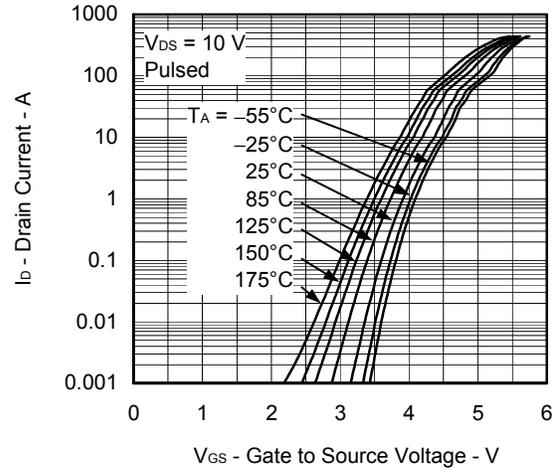
TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)



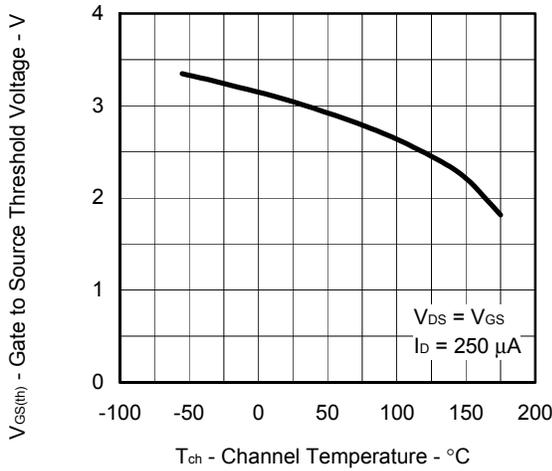
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



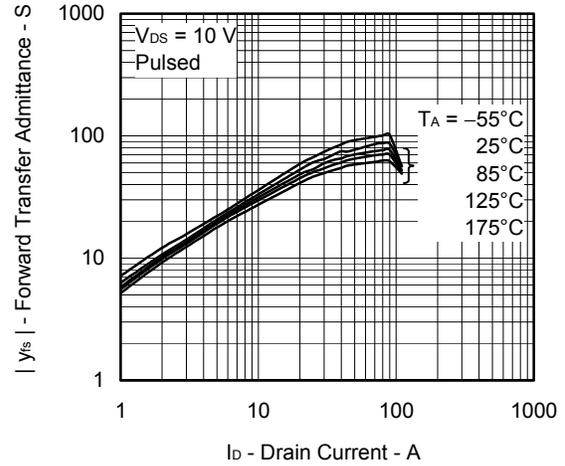
FORWARD TRANSFER CHARACTERISTICS



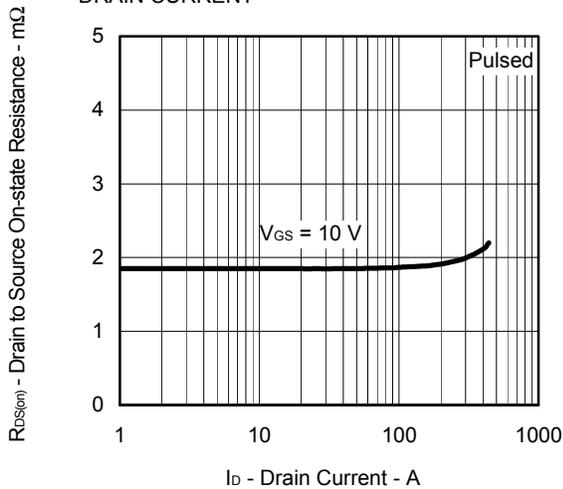
GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE



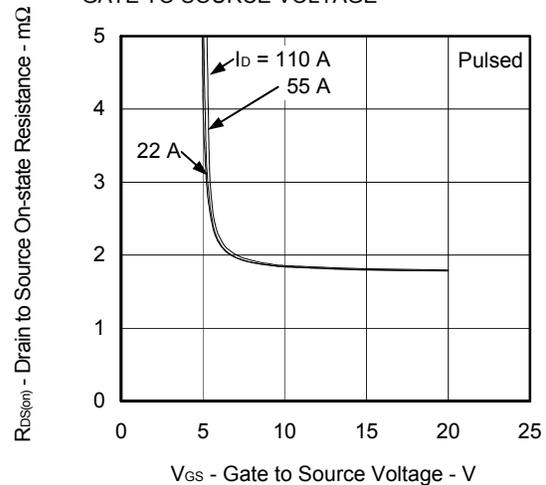
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



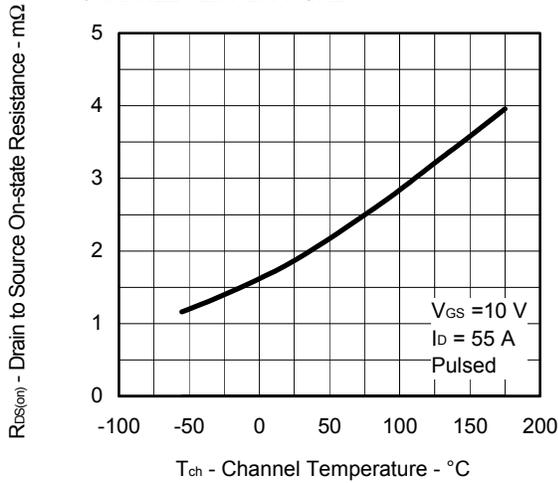
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



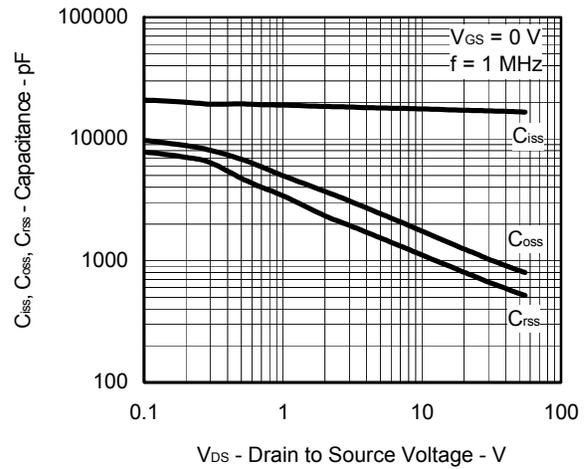
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



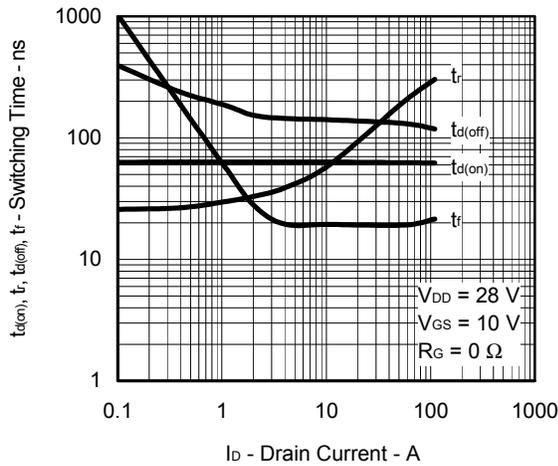
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



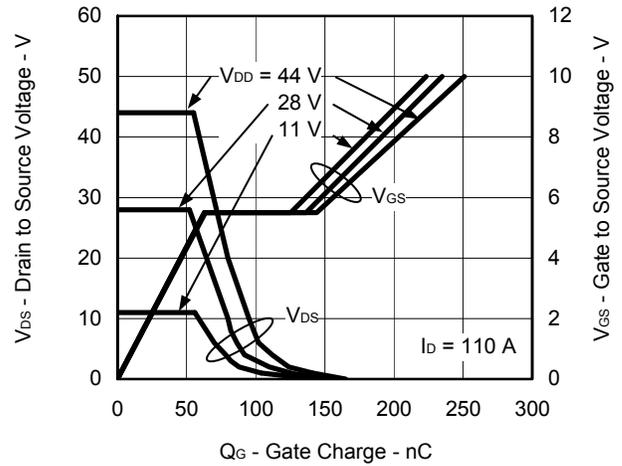
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



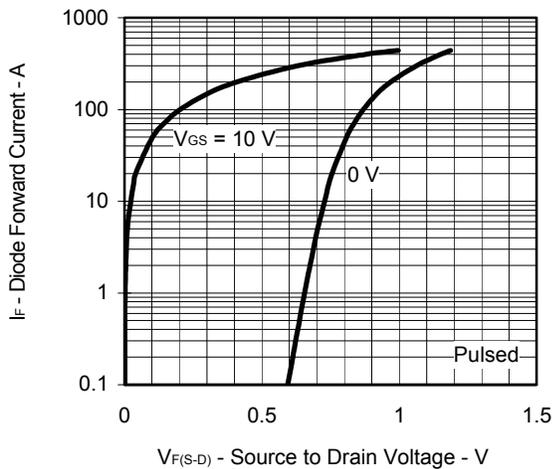
SWITCHING CHARACTERISTICS



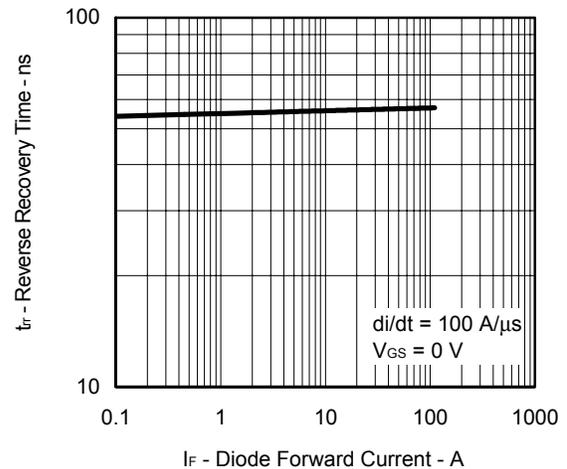
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT





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